

A circular black and white stamp. The text "OIPE" is at the top, "JC139" is at the top right, "JUN 18 2002" is in the center, and "PATENT & TRADEMARK OFFICE" is at the bottom.

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: EXAMINER: (TO BE ASSIGNED)

:

: GROUP ART UNIT: (TO BE ASSIGNED)

PRELIMINARY AMENDMENT

SIR:

IN THE CLAIMS

Before examining the captioned patent application, please amend the claims as shown in the Attachment, in which underlining and bracketing show the changes introduced into the previously-pending claims to arrive at the clean claims provided below:

1. (Amended) An electrode contact section incorporated in a semiconductor device, comprising:

- a first-conductivity-type semiconductor substrate;
- a second-conductivity-type impurity layer formed in one surface of the semiconductor substrate and having a thickness of not more than 1.0 μm from a surface of the semiconductor substrate;

a second-conductivity-type contact layer formed in the impurity layer and having a thickness of not more than 0.2 μm from the surface of the semiconductor substrate, the contact

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75.00 100
34.23 50